Memory Microcircuit - Page 1 of 1



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## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# End Application:

Pacer dawn

### **Features Provided:**

Hermetically sealed and burn in and programmable and positive outputs and electrostatic sensitive

#### **Inclosure Material:**

Ceramic and glass

### Inclosure Configuration:

Leadless flat pack

### Output Logic Form:

Transistor-transistor logic

### **Input Circuit Pattern:**

16 input

## **Criticality Code Justification:**

Cbbl

## Case Outline Source And Designator:

C-2 mil-m-38510

## **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## **Time Rating Per Chacteristic:**

30.00 nanoseconds propagation delay time, low to high level output and 30.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Pal

## Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## Terminal Type And Quantity:

20 leadless

#### Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

# Fiig:

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